

#### Features

- 390nA (Typ) Low Power Consumption
- Integrated 1.2V Voltage Reference
- Fast, 13us Propagation Delay
- Single-Supply Operation from +1.6V ~ +5.5V
- Low Offset Voltage: 3mV (Max)
- Rail-to-Rail Input and Output
- CMOS/TTL-Compatible Output

## No Phase Reversal for Overdriven Inputs

Internal Hysteresis for Clean Switching

- Operating Temperature: -40°C ~ +85°C
- Small Package:

GS8021 Available in SOT23-6 and SC70-6 Packages GS8021U Available in SOP-8 and MSOP-8 Packages

GS8021

## **General Description**

The GS8021 is ultra-low-power comparator with internal hysteresis, optimized for systems powered from a 3V or 5V supply. The device features high-speed response, low-power consumption, low offset voltage, and rail-to-rail input and output range.A 1.2V voltage reference is integrated for flexible application.

Propagation delay is 13us (100mV overdrive), while supply current is 390nA per comparator. The internal input hysteresis eliminates output switching due to internal input noise voltage. The maximum input offset voltage is 3mV, and the operating range is from 1.6V to 5.5V.

All devices are specified for the temperature range of  $-40^{\circ}$ C to  $+85^{\circ}$ C. The GS8021 single is available in Green SC70-6 and SOT23-6 packages. The GS8021U dual is available in Green SOP-8 and MSOP-8 packages. The GS8712 dual is available in Green SOP-8 and MSOP-8 packages.

## **Applications**

- Alarm and Monitoring Circuits
- Peak and Zero-crossing Detectors
- Logic Level Shifting or Translation
- RC Timers

- Window Comparators
- IR Receivers
- Portable Systems







## **Pin Configuration**



Figure 1. Pin Assignment Diagram









### **Absolute Maximum Ratings**

Condition	Min	Мах		
Power Supply Voltage (V <sub>DD</sub> to Vss)	-0.5V	+7.5V		
Analog Input Voltage (IN+ or IN-)	Vss-0.5V	V <sub>DD</sub> +0.5V		
PDB Input Voltage	Vss-0.5V	+7V		
Operating Temperature Range	-40°C	+85°C		
Junction Temperature	+1	60°C		
Storage Temperature Range	-55°C	+150°C		
Lead Temperature (soldering, 10sec)	+2	+260°C		
Package Thermal Resistance (T <sub>A</sub> =+25℃)				
SOP-8, θ <sub>JA</sub>	125	°C/W		
MSOP-8, θ <sub>JA</sub>	216°C/W			
SOT23-6, θ <sub>JA</sub>	190	190°C/W		
ESD Susceptibility				
НВМ	4	KV		
MM	3	V0C		

**Note:** Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## **Package/Ordering Information**

MODEL	CHANNEL	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION
GS8021	Single	GS8021-CR	SC70-6	Tape and Reel,3000	8021
630021	Single	GS8021-TR	SOT23-6	Tape and Reel,3000	8021
GS8021U Single	GS8021-CR	SC70-8	Tape and Reel,3000	021U	
	GS8021-TR	SOT23-8	Tape and Reel,3000	021U	
0000411	Cinala	GS8021U-SR	SOP-8	Tape and Reel,4000	GS8021U
GS8021U	Single	GS8021U-MR	MSOP-8	Tape and Reel,3000	GS8021U
	GS8021U2-SR	SOP-8	Tape and Reel,4000	GS8021U2	
GS8021U2	Single	GS8021U2-MR	MSOP-8	Tape and Reel,3000	GS8021U2







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## **Electrical Characteristics**

(At Vs = +5∨	V, V <sub>CM</sub> = 0V, C <sub>L</sub> = 15pF, and T <sub>A</sub>	∖ = +25°C,	unless otherwise noted.)

DADAMETED	SYMBOL	CONDITIONS				
PARAMETER SYMBOL		CONDITIONS	ТҮР	MIN	МАХ	UNITS
INPUT CHARACTERISTICS						
Input Offset Voltage	Vos	V <sub>CM</sub> = 0V	0.5		3	mV
Input Bias Current	IB		6			pА
Input Offset Current	I <sub>OS</sub>		4			pА
Input Hysteresis	V <sub>hys</sub>		4			mV
Common-Mode Voltage Range	V <sub>CM</sub>	V <sub>S</sub> = 5.5V	-0.1 to +5.6			V
Common-Mode Rejection Ratio	CMRR	$V_{\rm S}$ = 5V, $V_{\rm CM}$ = 0V to 5V	76	63		dB
OUTPUT CHARACTERISTICS						
	V <sub>OH</sub>		Vs - 0.1		Vs - 0.3	V
Output Voltage Swing from Rail	Vol	Vs=5V, I <sub>O</sub> = 1mA	114.6		300	mV
	I <sub>SOURCE</sub>	22	22			mA
Output Short-Circuit Current	I <sub>SINK</sub>	$V_{\rm S}$ = 5V, Out to $V_{\rm S}$	20			
POWER SUPPLY						
On another a Malta and Damage			1.6			V
Operating Voltage Range			5.5			V
Power Supply Rejection Ratio	PSRR	$V_{\rm S}$ = +1.6V to +5.5V, $V_{\rm CM}$ = 0V	102	74		dB
Quiescent Current / Comparator	Ι <sub>Q</sub>		390		440	nA
DYNAMIC PERFORMANCE (CL	= 15pF)					
	T <sub>dLH</sub>	V <sub>S</sub> = 3V, Overdrive = 10mV	11			μs
Propagation Delay (Low to High)		V <sub>S</sub> = 3V, Overdrive = 100mV	13			μs
	T <sub>dHL</sub>	V <sub>S</sub> = 3V, Overdrive = 10mV	18.6			μs
Propagation Delay (High to Low)		V <sub>S</sub> = 3V, Overdrive = 100mV	4.9			μs
	Tr	V <sub>S</sub> = 3V, Overdrive = 10mV	10			ns
Rise Time		V <sub>S</sub> = 3V, Overdrive = 100mV	9			ns
	T <sub>f</sub>	V <sub>S</sub> = 3V, Overdrive = 10mV	18			ns
Fall Time		V <sub>S</sub> = 3V, Overdrive = 100mV	10			ns
Voltage Reference			•	•		
Reference Voltage	V <sub>ref</sub>	I <sub>ref</sub> =0A	1214	1190	1238	mV
Reference Voltage				150		µV/°C
Reference Output Current				4		mA







### **Typical Performance characteristics**

At  $T_A$ =+25°C,  $V_S$ =+5V, and  $C_L$ =15pF, unless otherwise noted.



Reference Voltage vs. Temperature 1216 Vs=5V ∠ 1214 1212 **∧** Vs=1.6V 1210 1208 1206 -50 -25 75 100 0 25 50 temperature(25°C/div)

V<sub>ref</sub>(2mV/div)

Vout(0.5V/div) Vin(50mV/div)

Output Short-Circuit (Source) Current vs. Temperature



Progation Delay (L-H&H-L)



#### Time(50us/div)



Output Short-Circuit (Sink) Current vs. Temperature



Progation Delay (L-H&H-L)



Time(50us/div)





## **Application Note**

#### Size

GS8021 comparator is ultra-low-power, high-speed and suitable for a wide range of general-purpose applications. The small footprints of the GS8021 package saves space on printed circuit boards and enable the design of smaller electronic products. The GS8021 interfaces directly to CMOS and TTL logics.

#### **Power Supply Bypassing and Board Layout**

GS8021 operates from a single 1.6V to 5.5V supply or dual  $\pm 0.8V$  to  $\pm 2.75V$  supplies. For best performance, a  $0.1\mu$ F ceramic capacitor should be placed close to the V<sub>DD</sub> pin in single supply operation. For dual supply operation, both V<sub>DD</sub> and V<sub>SS</sub> supplies should be bypassed to ground with separate  $0.1\mu$ F ceramic capacitors.

#### Low Supply Current

The low supply current (typical 390nA per channel) of GS8021 will help to maximize battery life. They are ideal for battery powered systems.

#### **Operating Voltage**

GS8021 operates under wide input supply voltage (1.6V to 5.5V). In addition, all temperature specifications apply from -40 °C to +85 °C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime

#### **Rail-to-Rail Input**

The input common-mode range of GS8021 extends 100mV beyond the supply rails ( $V_{SS}$ -0.1V to  $V_{DD}$ +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

#### **Internal Hysteresis**

Because of noise or undesired parasitic feedback, high-speed comparators oscillate in the linear region. Oscillation tends to occur when the voltage on one input is at or equal to the voltage on the other input. The GS806 family eliminates this undesired oscillation by integrating an internal hysteresis of 4mV.

The hysteresis in a comparator creates two trip points: one for the rising input voltage and one for the falling input voltage (Figure 2). The difference between two trip points is the hysteresis, while the average of two trip points is the offset voltage. When the comparator's input voltages are equal, the hysteresis effectively causes one comparator input voltage to move quickly past the other, thus taking the input out of the region where oscillation occurs.



Figure 2. Comparator's hysteresis and offset

#### **External Hysteresis**

Greater flexibility in selecting hysteresis is achieved by using external resistors. Hysteresis reduces output chattering when one input is slowly moving past the other.







### Non-Inverting Comparator with Hysteresis



Figure 3. Non-Inverting Comparator with Hysteresis

A non-inverting comparator with hysteresis requires a two-resistor network, as shown in Figure 3 and a voltage reference (V<sub>R</sub>) at the inverting input.

$$\begin{split} \mathbf{V}_{\mathrm{TH}} &= \frac{R_{\mathrm{G}} + R_{\mathrm{F}}}{R_{\mathrm{F}}} \times \mathbf{V}_{\mathrm{R}} \\ \mathbf{V}_{\mathrm{TL}} &= \frac{R_{\mathrm{G}} + R_{\mathrm{F}}}{R_{\mathrm{F}}} \times \mathbf{V}_{\mathrm{R}} - \frac{R_{\mathrm{G}}}{R_{\mathrm{F}}} \times \mathbf{V}_{\mathrm{DD}} \\ \mathbf{V}_{\mathrm{HYS}} &= \frac{R_{\mathrm{G}}}{R_{\mathrm{F}}} \times \mathbf{V}_{\mathrm{DD}} \end{split}$$

#### Inverting Comparator with Hysteresis



Figure 4. Inverting Comparator with Hysteresis

The inverting comparator with hysteresis requires a three-resistor network that is referenced to the comparator supply voltage  $(V_{DD})$ , as shown in Figure 4.

$$\begin{split} \mathbf{V}_{\text{TH}} &= \frac{R_{\text{G2}}}{R_{\text{G1}} \parallel R_{\text{F}} + R_{\text{G2}}} \times \mathbf{V}_{\text{DD}} \\ \mathbf{V}_{\text{TL}} &= \frac{R_{\text{G2}} \parallel R_{\text{F}}}{R_{\text{G2}} \parallel R_{\text{F}} + R_{\text{G1}}} \times \mathbf{V}_{\text{DD}} \\ \mathbf{V}_{\text{HYS}} &= \frac{R_{\text{G1}} \parallel R_{\text{G2}}}{R_{\text{G1}} \parallel R_{\text{G2}} + R_{\text{F}}} \times \mathbf{V}_{\text{DD}} \end{split}$$







## **Typical Application Circuits**

#### Line Receiver

A Line Receiver using GS8021 is shown in Figure 5. Resistors  $R_{G1}$  and  $R_{G2}$  set the bias point at the comparator's inverting input.  $R_{IN}$  should be same as  $R_{G1}||R_{G2}$  to get a better match. GS8021 detects the voltage of the Coax Line, and outputs logic high or logic low quickly with no glitch.



Figure 5. Line Receiver

#### **IR Receiver**

GS8021 is an ideal candidate to be used as an infrared receiver shown in Figure 6. The infrared photo diode creates a current relative to the amount of infrared light present. The current creates a voltage across  $R_{IN}$ . When this voltage level cross the voltage applied by the voltage divider to the inverting input, the output transitions. Optional  $R_F$  provides additional hysteresis for noise immunity.



Figure 6. IR Receiver







#### Oscillator

A oscillator using GS8021 is shown in Figure 7. Resistors  $R_{G1}$  and  $R_{G2}$  set the bias point at the comparator's inverting input. The period of oscillator is set by the time constant of  $R_{C}$  and  $C_{IN}$ . The maximum frequency is limited by the large signal propagation delay of the comparator. GS8021 is low propagation delay guarantees the high frequency oscillation. If  $R_{G1}=R_{G2}=R_{F}$ , then the frequency of the oscillator is:





Figure 7. Oscillator







## **Package Information**

SOT23-6



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
А	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950 BSC		0.037	BSC
e1	1.900 BSC		0.075	BSC
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°
	-			















Dimensions In Millimeters		Dimensions	
		In Inches	
Min	Мах	Min	Max
0.900	1.100	0.035	0.043
0.000	0.100	0.000	0.004
0.900	1.000	0.035	0.039
0.150 0.350		0.006	0.014
0.080	0.150	0.003	0.006
2.000	2.200	0.079	0.087
1.150	1.350	0.045	0.053
2.150	2.450	0.085	0.096
0.650TYP		0.026TYP	
1.200	1.400	0.047	0.055
0.525REF		0.021R	EF
0.260 0.460		0.010	0.018
0°	8°	0°	8°
	In Millin Min 0.900 0.000 0.150 0.080 2.000 1.150 2.150 0.650T 1.200 0.525R 0.260	In Millimeters   Min Max   0.900 1.100   0.000 0.100   0.900 1.000   0.900 1.000   0.900 1.000   0.900 1.000   0.150 0.350   0.080 0.150   2.000 2.200   1.150 1.350   2.150 2.450   0.650TYP 1.200   1.200 1.400   0.525REF 0.260   0.260 0.460	In Millimeters In Inch   Min Max Min   0.900 1.100 0.035   0.000 0.100 0.000   0.900 1.000 0.035   0.150 0.350 0.006   0.450 0.150 0.003   0.080 0.150 0.003   2.000 2.200 0.079   1.150 1.350 0.045   2.150 2.450 0.085   0.650T/P 0.026T 0.021R   0.525REF 0.021R 0.0210















Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
с	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
e	0.650 BSC		0.026 BSC	
L	0.400	0.800	0.016	0.031
θ	0°	6°	0°	6°







SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
с	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27 BSC		0.050	BSC
L	0.400	1.270	0.016	0.050
6	0°	8°	0°	8°



